Ordering number: EN2960

NPN Triple Diffused Planar Silicon Transistor



2SC4002

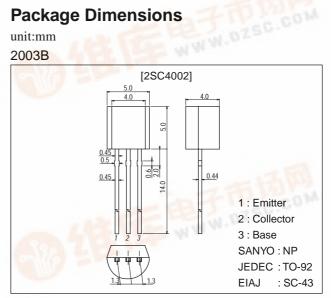
High-Voltage Driver Applications

Features

- · High breakdown voltage.
- · Adoption of MBIT process.
- · Excellent hFE linearity.

Package Dimensions

unit:mm 2003B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		400	V
Collector-to-Emitter Voltage	V _{CEO}		400	V
Emitter-to-Base Voltage	V _{EBO}	110	5	V
Collector Current	lc		200	mA
Collector Current (Pulse)	I _{CP}	a sub-Care Lit	400	mA
Collector Dissipation	PC	AND REAL PROPERTY.	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg	61///3	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	ICBO	V _{CB} =300V, I _E =0			0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0			0.1	μΑ
DC Current Gain	hFE	V _{CE} =10V, I _C =50mA	60*		200*	777
Gain-Bandwidth Product	f _T	V _{CE} =30V, I _C =10mA	40	70		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =50mA, I _B =5mA		M 07	0.6	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =50mA, I _B =5mA	ALM.	7.	1.0	V

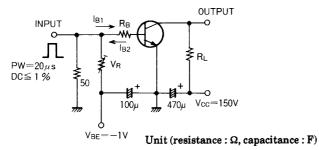
*: The 2SC4002 is classified by 50mA h_{FE} as follows:

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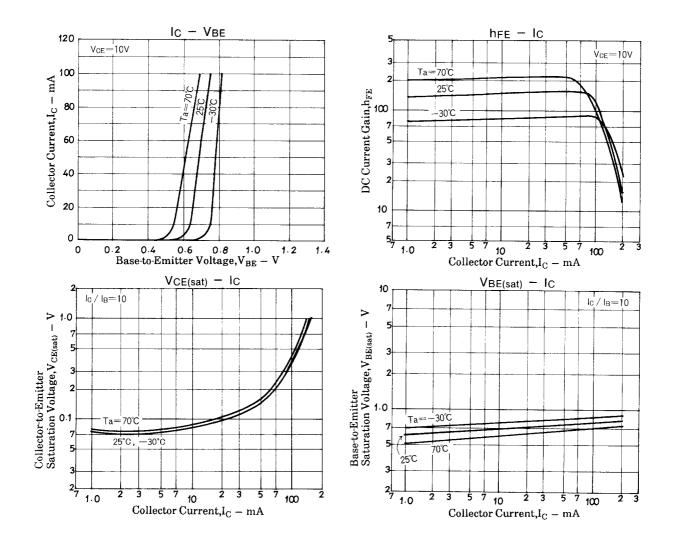
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

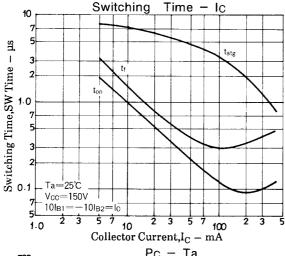
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =10μA, I _E =0	400			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	5			V
Output Capacitance	C _{ob}	V _{CB} =30V, f=1MHz		4		pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =30V, f=1MHz		3		pF
Turn-ON Time	ton	See specified test circuit.		0.25		μs
Turn-OFF Time	toff	See specified test circuit.		5.0		μs

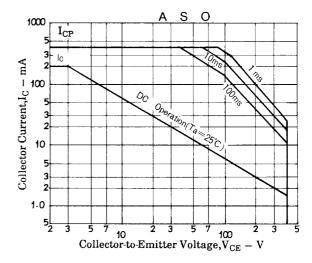
Switching Time Test Circuit

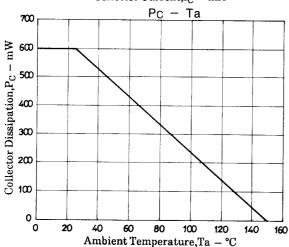


 $10I_{B1} = -10I_{B2} = I_C = 50 \text{mA}$ $R_L = 3k\Omega, R_B = 200\Omega \text{ at } I_C = 50 \text{mA}$









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